
Status and Prospects of TPC Module and Prototype at High Luminosity Z

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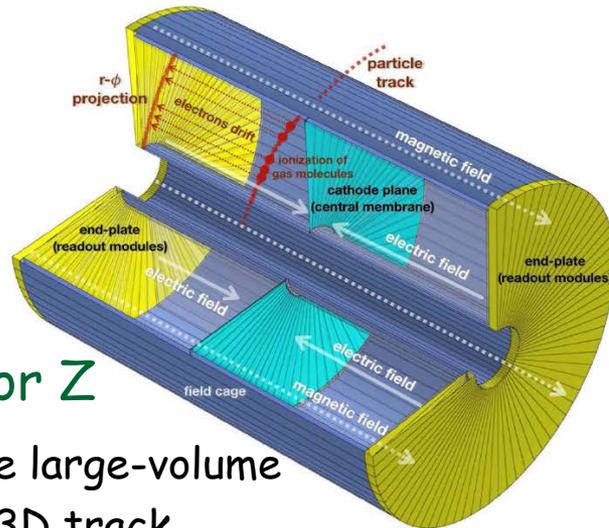
Tsinghua University

IAS zoom meeting, Jan., 21, 2021

Outline

- **Motivation**
- **TPC module R&D**
- **TPC prototype R&D**
- **FEE ASIC R&D**
- **Summary**

Motivation



TPC critical R&D for Z

- TPC can provide large-volume high-precision 3D track measurement with **stringent material budget**
- In order to achieve **the high spatial resolution** (<100um in all drift length), small pads (e.g.1mmx6mm) are needed, resulting **~1million channels** of readout electronics
- Need **low power consumption** readout electronics working at continuous mode
- Need effectively **reduce ions**

Momentum resolution (B=3.5T) $\delta(1/p_t \approx 10^{-4}/GeV/c)$

δ_{point} in $r\phi$	<100 μm
δ_{point} in rZ	0.4-1.4 mm
Inner radius	329 mm
Outer radius	1800 mm
Drift length	2350 mm
TPC material budget	$\approx 0.05X_0$ incl. field cage $< 0.25X_0$ for readout endcap
Pad pitch/no. padrows	$\approx 1 \text{ mm} \times (4\sim 10\text{mm}) / \approx 200$
2-hit resolution	$\approx 2 \text{ mm}$
Efficiency	$>97\%$ for TPC only ($p_t > 1\text{GeV}$) $>99\%$ all tracking ($p_t > 1\text{GeV}$)

CEPC High Luminosity Parameters after CDR

	<i>tt</i>	<i>Higgs</i>	<i>W</i>	<i>Z</i>	
Number of IPs	2	2	2	2	2
Energy (GeV)	180	120	80	45.5	45.5
Circumference (km)	100	100	100	100	100
SR loss/turn (GeV)	8.53	1.73	0.33	0.036	0.036
Half crossing angle (mrad)	16.5	16.5	16.5	16.5	16.5
Piwiński angle	1.16	4.87	9.12	24.9	24.9
N_p/bunch (10^{10})	20.1	16.3	11.6	15.2	15.2
Bunch number (bunch spacing)	37 (4.45 μs)	214 (0.7ns)	1588 (0.2 μs)	3816 (86ns)	11498 (26ns)
Beam current (mA)	3.5	16.8	88.5	278.8	839.9
SR power /beam (MW)	30	30	30	10	30
Bending radius (km)	10.7	10.7	10.7	10.7	10.7
Phase advance of arc cell	#1: CEPC Status				
Momentum compaction (10^{-5})	Speaker: Jie GAO (Institute of High Energy Physics, Chinese Academy of Sciences)				
β_{IP} x/y (m)	CEPC Status and T...				
Emittance x/y (nm)					
Transverse σ_{IP} (um)					
$\epsilon_x/\epsilon_y/\text{IP}$					
V_{RF} (GV)	9.52	2.27	0.47	0.1	0.1
f_{RF} (MHz) (harmonic)	650 (216816)	650 (216816)	650 (216816)	650 (216816)	650 (216816)
Nature bunch length σ_x (mm)	2.23	2.25	2.4	2.75	2.75
Bunch length σ_z (mm)	2.66	4.42	5.3	9.6	9.6
HOM power/cavity (kw)	0.45 (5cell)	0.48 (2cell)	0.79 (2cell)	2.0 (2cell)	3.02 (1cell)
Energy spread (%)	0.17	0.19	0.11	0.12	0.12
L_{max}/IP ($10^{34}\text{cm}^{-2}\text{s}^{-1}$)	0.5	5.0	18.7	35.0	105.5

- **TPC module R&D**

TPC detector module@ IHEP

- Study with GEM-MM module
 - New assembled module
 - Active area: $100\text{mm} \times 100\text{mm}$
 - X-tube ray and ^{55}Fe source
 - Bulk-Micromegas assembled from Saclay
 - Standard GEM from CERN
 - Avalanche gap of MM: $128\mu\text{m}$
 - Transfer gap: 2mm
 - Drift length: $2\text{mm} \sim 200\text{mm}$
 - pA current meter: Keithley 6517B
 - Current recording: Auto-record interface by LabView
 - Standard Mesh: 400LPI
 - High mesh: 508 LPI
 - Pixel option for the consideration in 2020

DOI: 10.1088/1748-0221/12/04/P0401 JINST, 2017.4
DOI: 10.1088/1674-1137/41/5/056003, CPC, 2016.11
DOI: 10.7498/aps.66.072901 Acta Phys. Sin. 2017,7
DOI: 10.1142/S2010194518601217 (SCI) 2018
DOI: 10.1088/1748-0221/13/04/T04008 (SCI) 2018
DOI: 10.1007/978-981-13-1316-5_20 (SCI) 2018

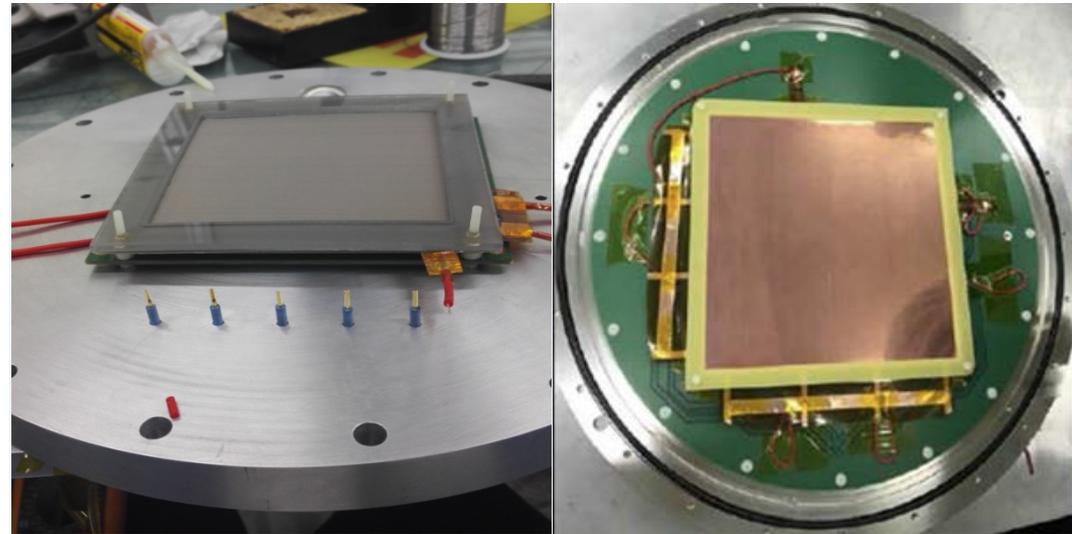
$50 \times 50\text{mm}^2$
2015-2016



$100 \times 100\text{mm}^2$
2017-2018



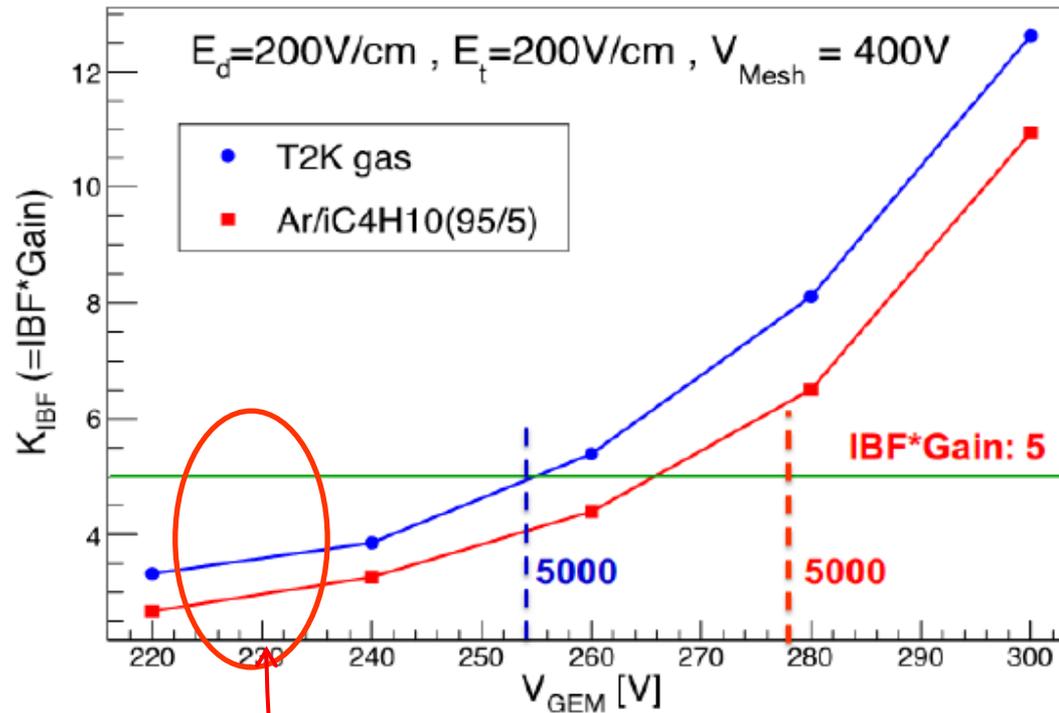
$200 \times 200\text{mm}^2$
2019-2020



GEM-MM detector cathode

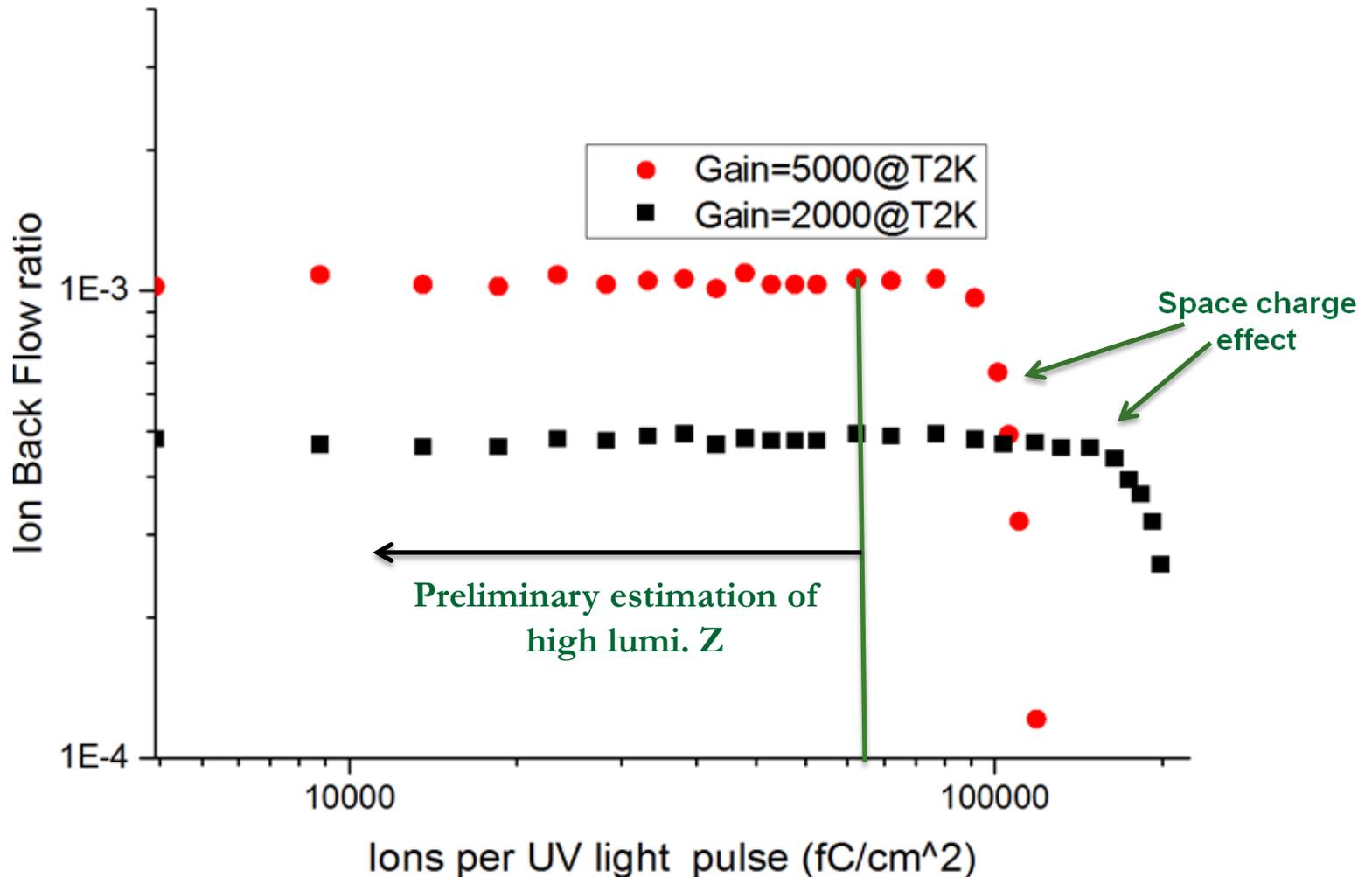
GEM+MM

Micronegas + GEM detector module @IHEP



- ❑ $IBF \times Gain$ ratio can meet less than 2 at the lower gain under two mixture gases
- ❑ Lower gain and lower IBF ratio

Space charge effect at the different gain

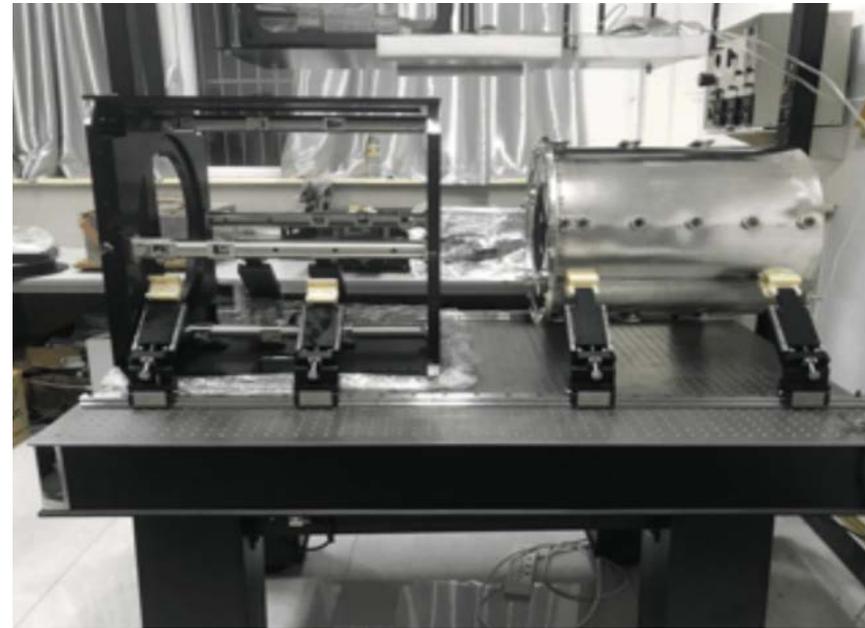
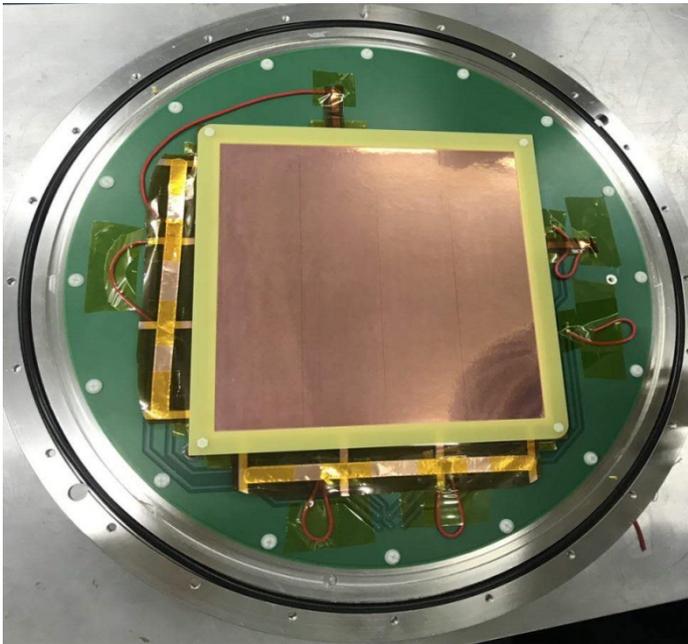
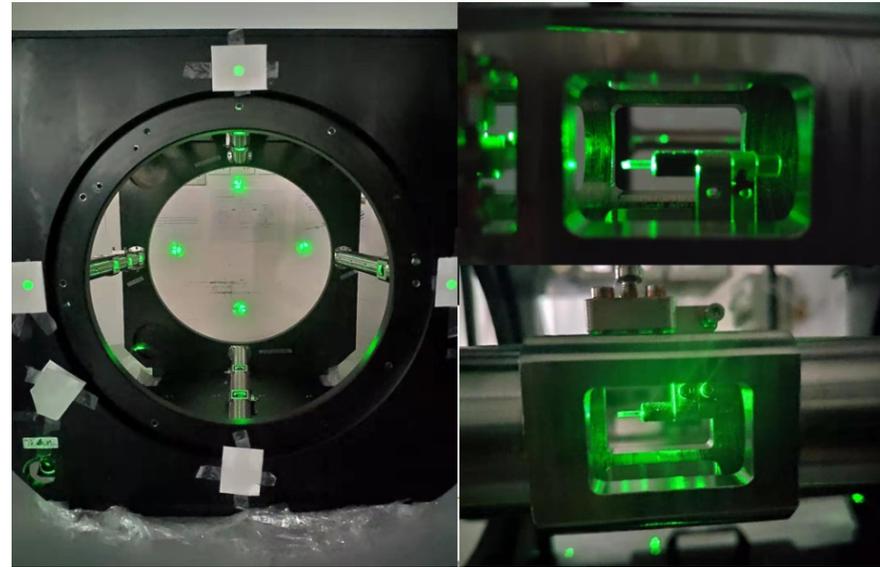


- ❑ Preliminary estimation of the high luminosity Z
- ❑ There are more safe factor when the detector will run at the lower gain (eg.2000-3000)

- **TPC prototype R&D**

TPC detector prototype

- Study of TPC prototype with 42 UV laser beams
- Main parameters
 - Drift length: $\sim 500\text{mm}$, Active area: 200mm^2
 - Integrated 266nm laser beam
 - GEMs/Micromegas as the readout

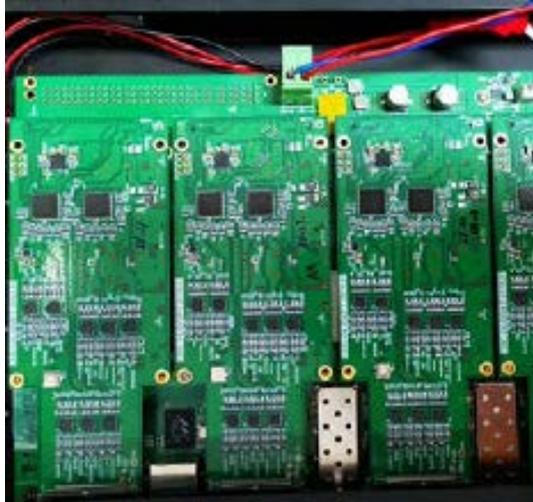


Electronics and DAQ

- ❑ Amplifier and FEE
 - ❑ CASAGEM chip
 - ❑ 16Chs/chip
 - ❑ 4chips/Board
 - ❑ Gain: 20mV/fC
 - ❑ Shape time: 20ns

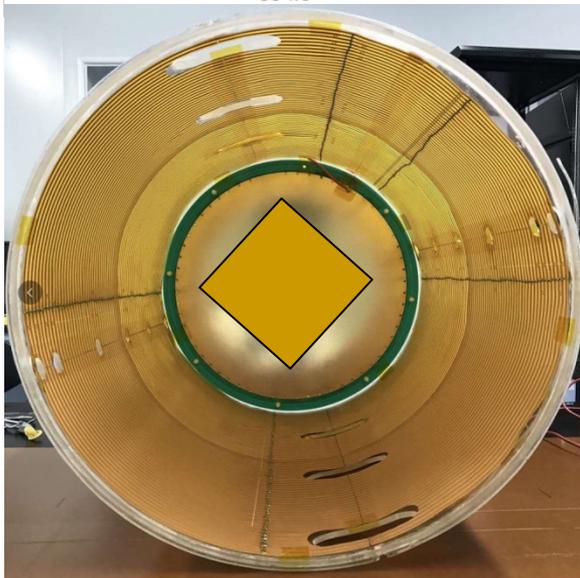
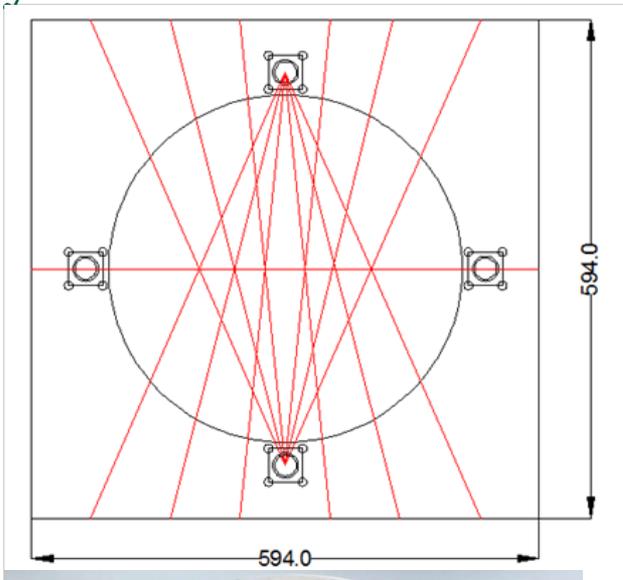


- ❑ DAQ
 - ❑ FPGA+ADC
 - ❑ 4 module/board
 - ❑ 64Chs/module
 - ❑ Sample: 40MHz
 - ❑ 1280chs



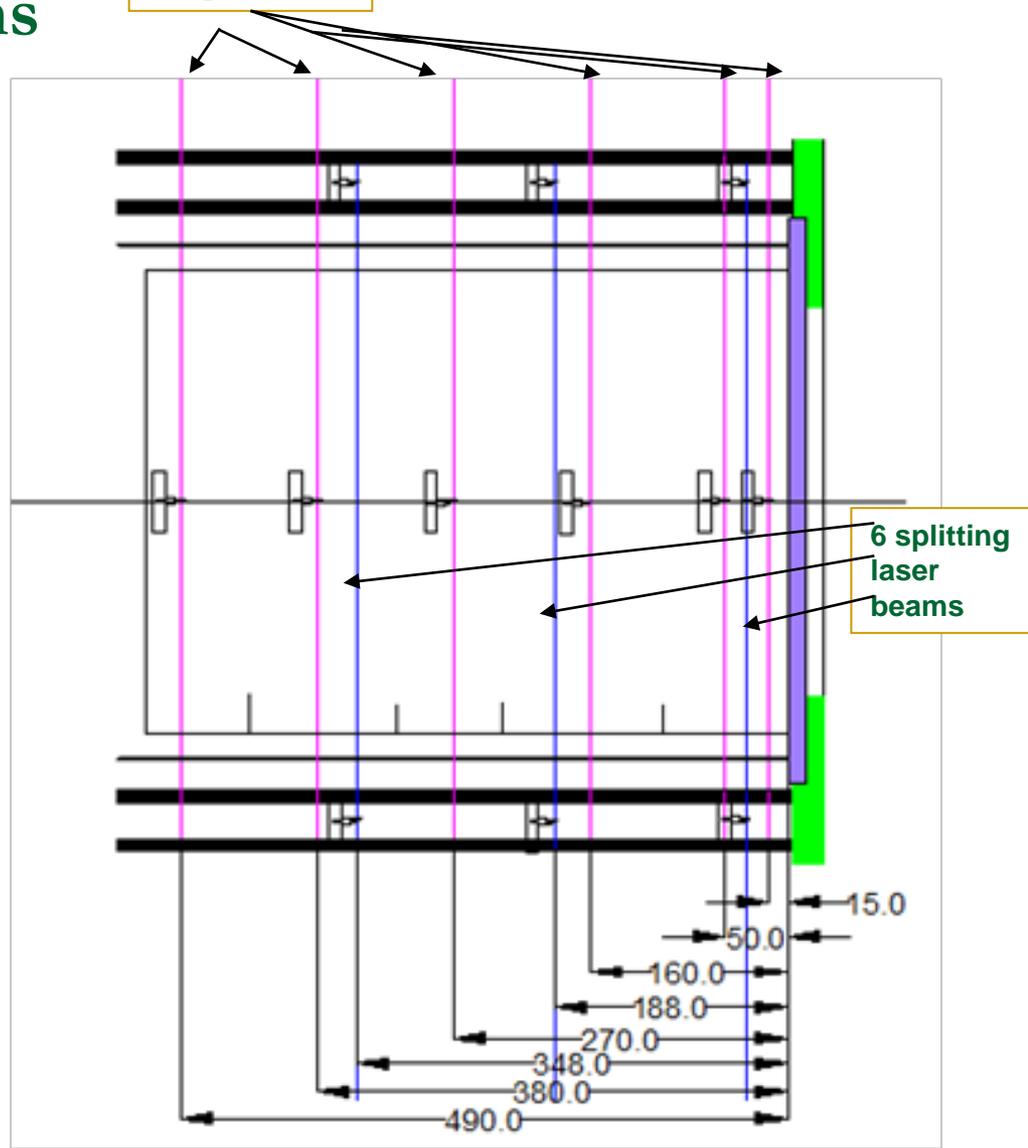
FEE Electronics and DAQ setup photos

Layout of UV laser beams



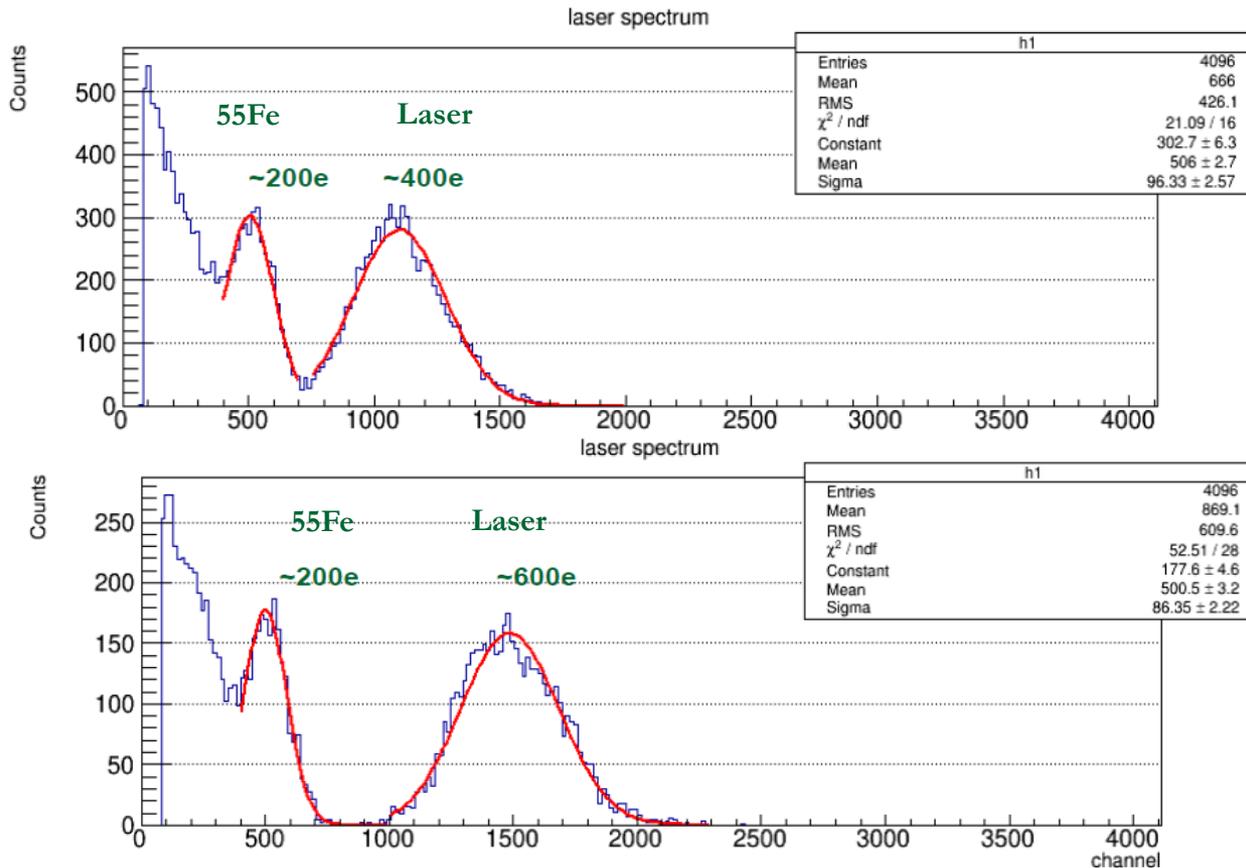
Laser map in X-Y direction

Single beam



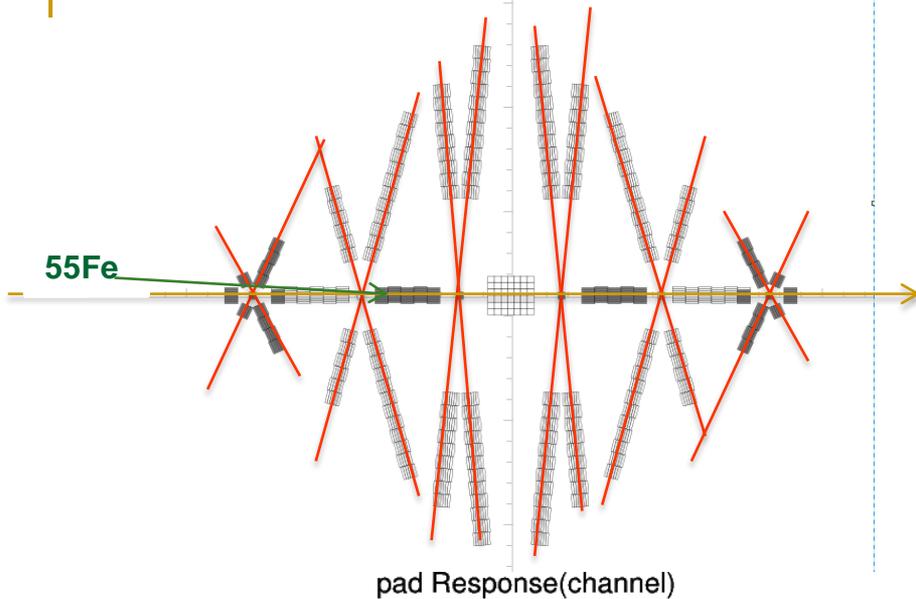
Laser map along drift length

Comparison of UV laser and ^{55}Fe

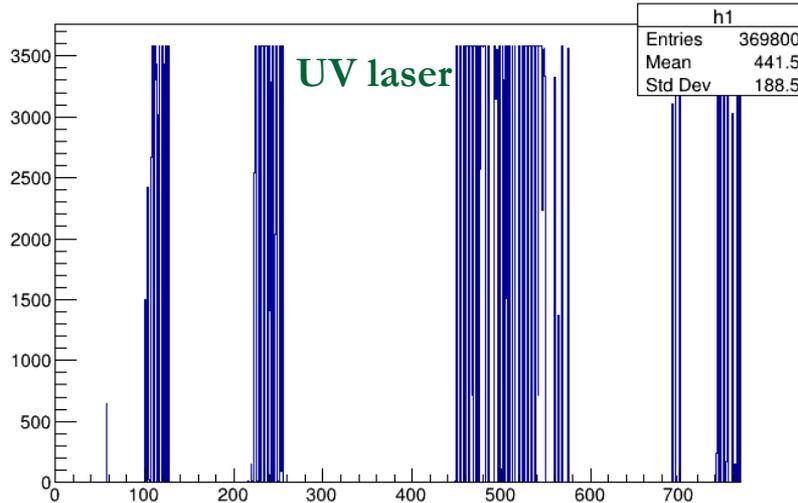


- Same test conditions under the same working gases and high voltage
- The ionization results indicate that the number for Ar:CO₂(90:10)-gas and T2K-gas are similar for the ionization density.
- About the gas purity, the experiment shows all mixture gas of the purity of isobutane is 99.9% despite other gases are 99.999%.

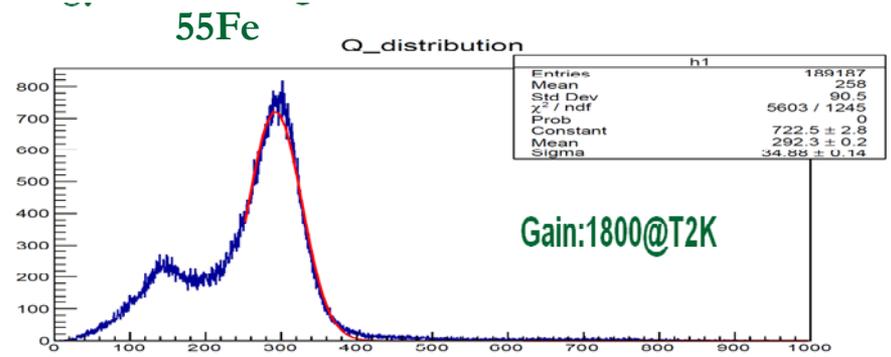
Energy spectrum@T2K gas



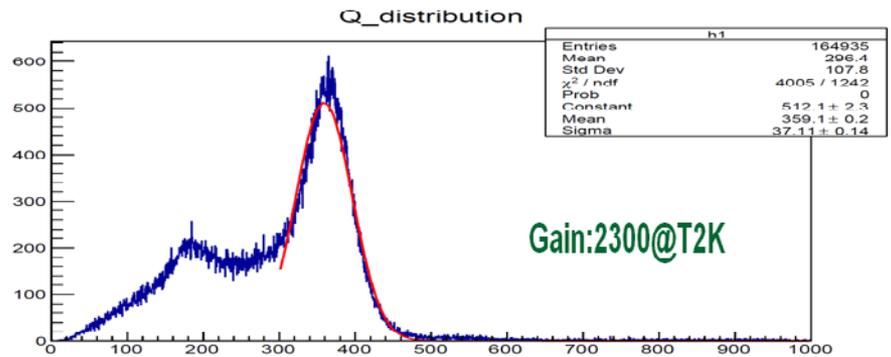
pad Response(channel)



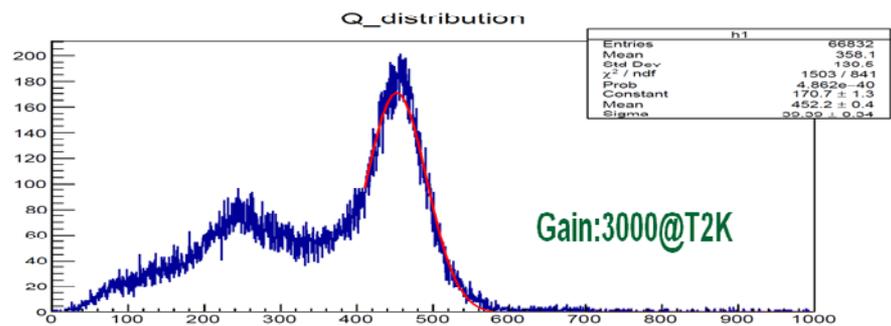
All pads response and energy spectrum @laser and 55Fe



Gain:1800@T2K

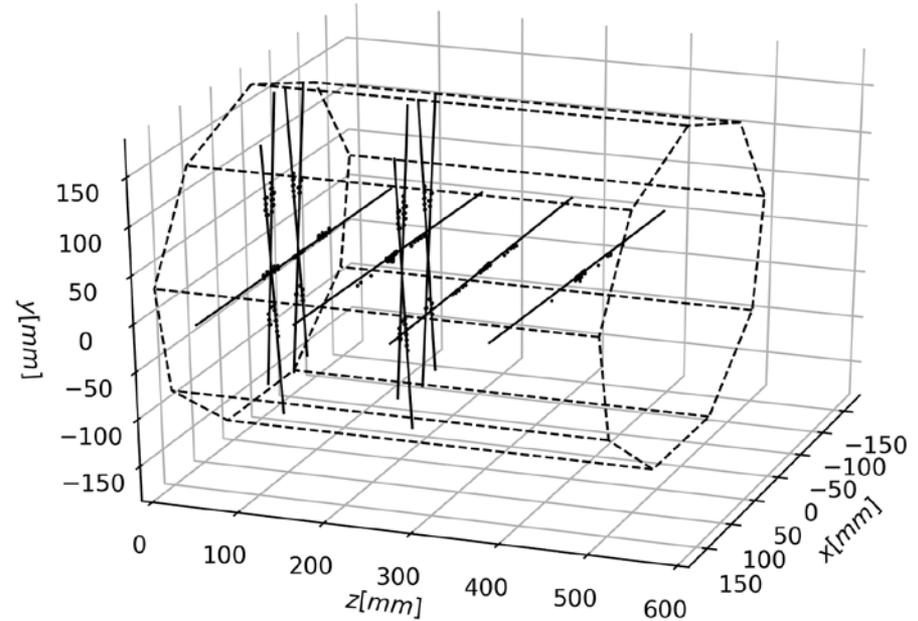
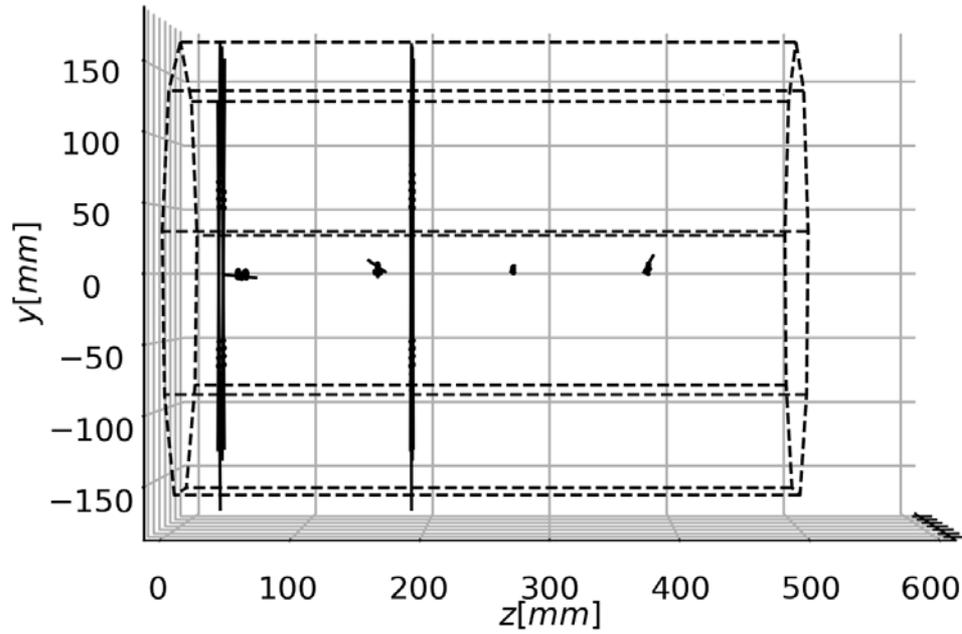


Gain:2300@T2K



Gain:3000@T2K

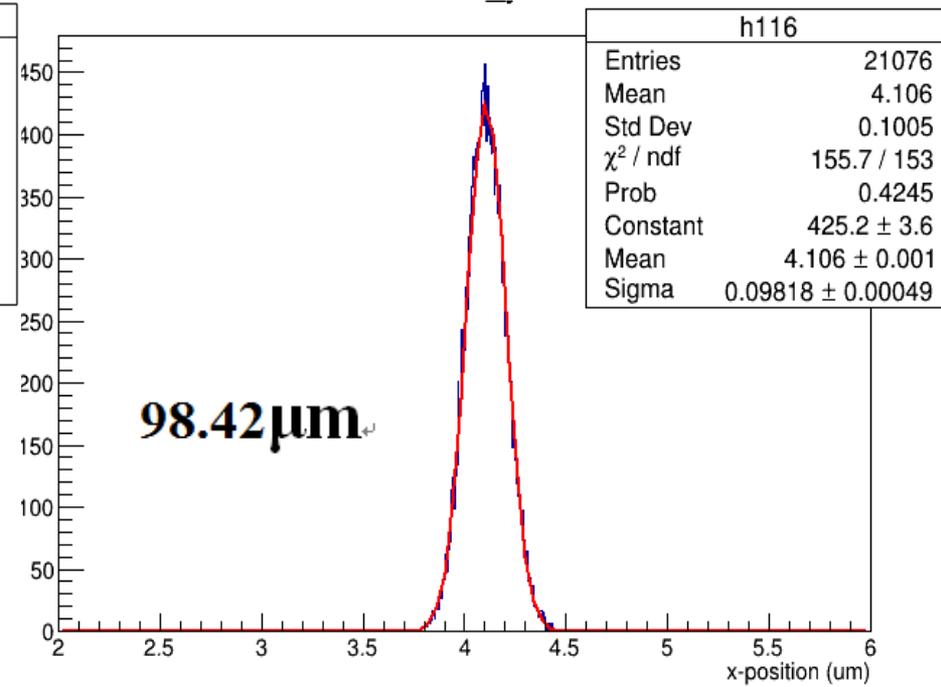
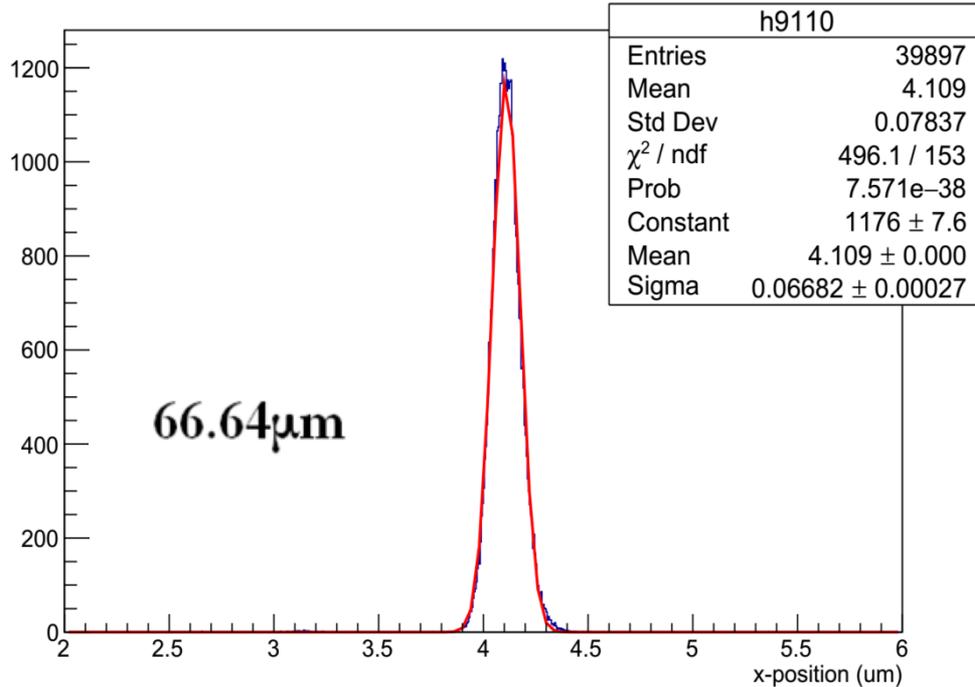
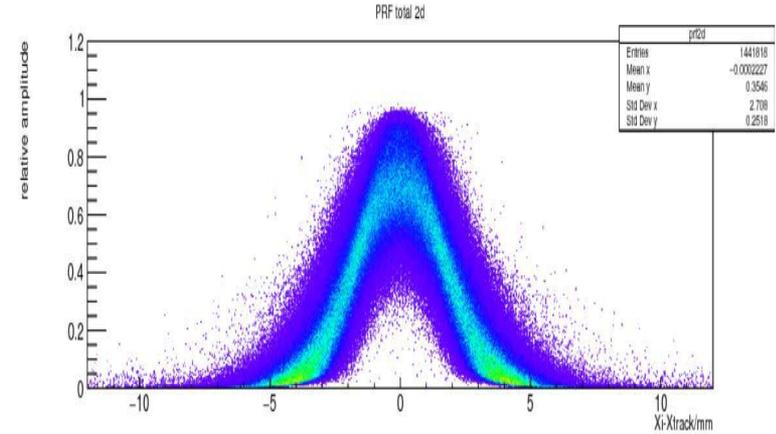
Laser tracks in chamber@T2K gas



- ❑ Same of working gas@T2K, same of high voltage, same of test conditions
- ❑ Different of GEMs@ 320V
- ❑ Triple GEMs to double GEMs
- ❑ No discharge

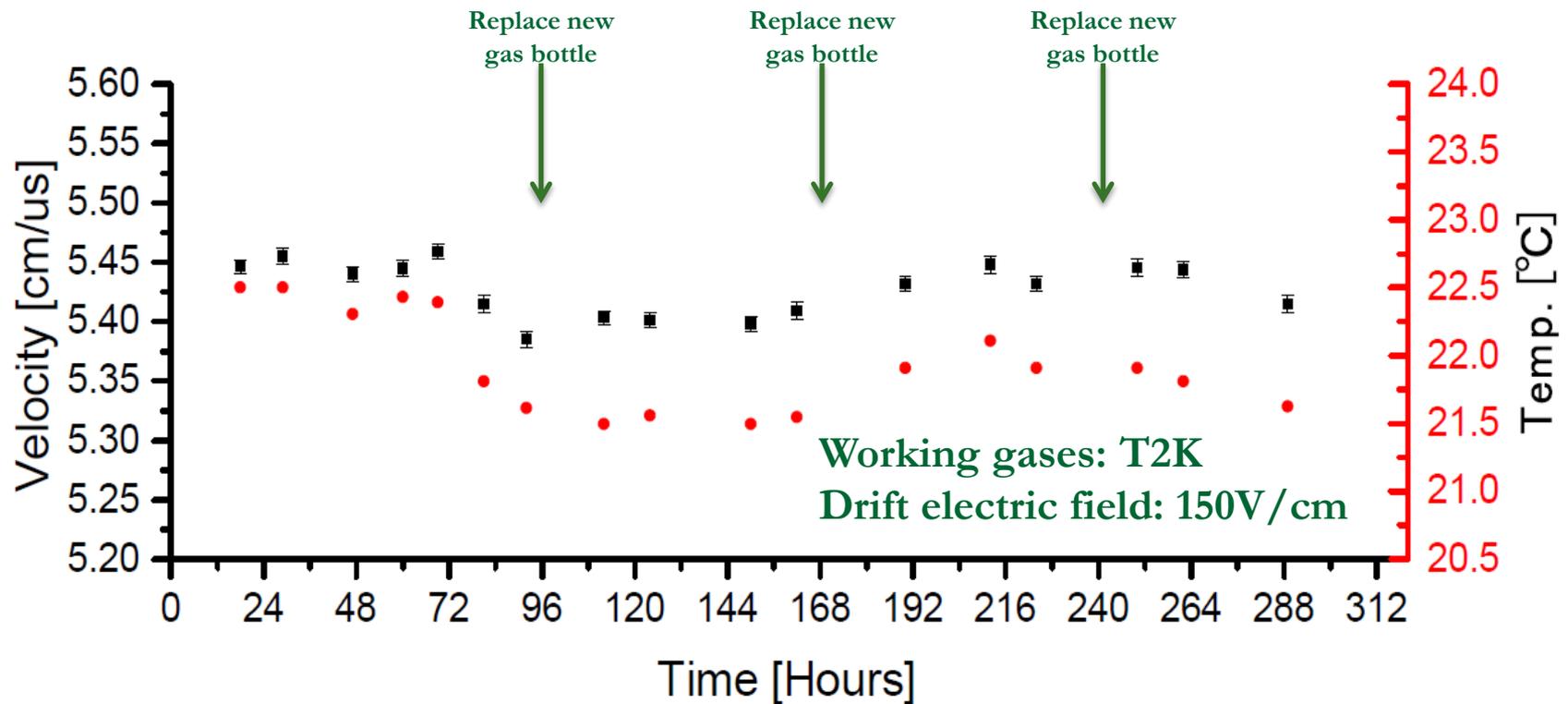
Space resolution

$$PRF(x, r, w) = \frac{\exp[-4\ln 2(1-r)x^2/w^2]}{1+4rx^2/w^2}$$



Space resolution at the different drift length
 Left(drift length: 50mm) Right(drift length: 270mm)

Drift velocity measurement



- ❑ Two weeks of continuous testing
- ❑ Room temperature recorded
- ❑ Comparison of the drift velocity and the temperature
- ❑ **266nm UV laser can work well when it can be as the calibration and monitor**

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- **FEE ASIC chip R&D**

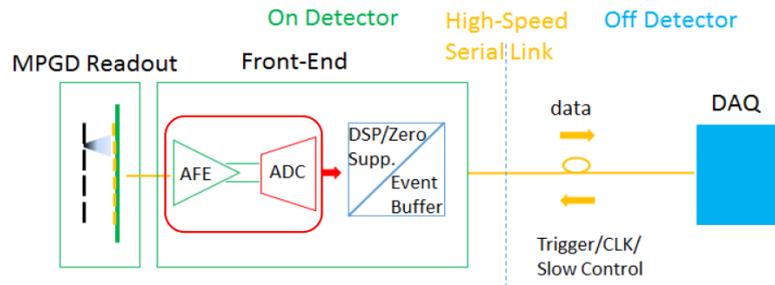
Current TPC readout ASICs

- Waveform sampling (8-10 bit, $\sim 10\text{MS/s}$) is required for TPC signal processing
- Direct ADC sampling is more preferable than SCA for high rate applications
- Lower power consumption \rightarrow less cooling \rightarrow less material

	PASA/ALTRO	AGET	Super-ALTRO	SAMPA
TPC	ALICE	T2K	ILC	ALICE upgrade
Pad size	4x7.5 mm ²	6.9x9.7 mm ²	1x6 mm ²	4x7.5 mm ²
Pad channels	5.7 x 10 ⁵	1.25 x 10 ⁵	1-2 x 10 ⁶	5.7 x 10 ⁵
Readout Chamber	MWPC	MicroMegas	GEM/MicroMegas	GEM
Gain	12 mV/fC	0.2-17 mV/fC	12-27 mV/fC	20/30 mV/fC
Shaper	CR-(RC) ⁴	CR-(RC) ²	CR-(RC) ⁴	CR-(RC) ⁴
Peaking time	200 ns	50 ns-1 μ s	30-120 ns	80/160 ns
ENC	385 e	850 e @ 200ns	520 e	482 e @ 180ns
Waveform Sampler	ADC	SCA	ADC	ADC
Sampling frequency	10 MSPS	1-100 MSPS	40 MSPS	20 MSPS
Dynamic range	10 bit	12 bit(external)	10 bit	10 bit
Power consumption	32 mW/ch	<10 mW/ch	47.3 mW/ch	8 mW/ch
CMOS Process	250 nm	350 nm	130 nm	130 nm

Specifics of ASIC using 65nm

- In order to reduce the power consumption:
 - Using more advanced 65 nm CMOS process favoring digital logics
 - Reducing analog circuits:
 - CR-(RC)ⁿ → CR-RC, moving high order shaping to digital domain
 - ADC structure : pipeline → SAR (Successive Approximation Register)
- So far only the AFE and the ADC parts have been implemented

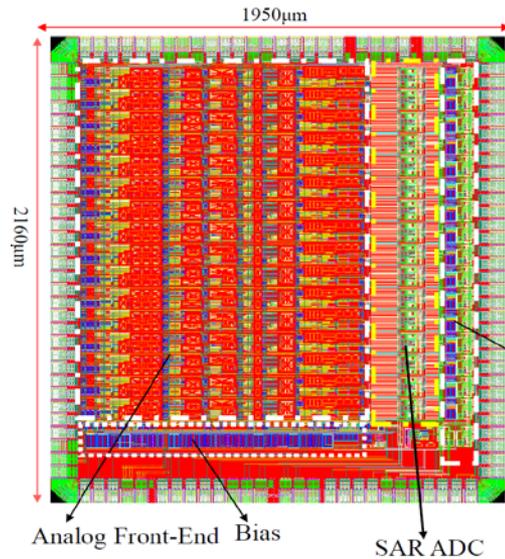


- AFE + waveform sampling ADC + direct output
- Process: TSMC 65nm LP
- Power supply: 1.2V

AFE(Analog Front-End)	
Signal Polarity	Negative
Detector Capacitance	5-20 pF
Shaper	CR-RC
Shaping Time	160 ns
ENC (Equivalent Noise Charge)	<500 e @ 10pF
Dynamic Range	120 fC max.
Gain	10-40 mV/fC
INL (Integrated Non-Linearity)	<1%
Crosstalk	<1%
Power Consumption (AFE)	<2.5 mW/ch

SAR-ADC	
Input Range	-0.6 V ~ 0.6 V diff.
Resolution	10 bit
Sampling Rate	40 MS/s
DNL	<0.6 LSB
INL	<0.6 LSB
SFDR @ 2MHz, 40MSPS	68 dBc
SINAD	57 dB
ENOB	>9.2 bit @ 2MHz
Power Consumption (ADC)	<2.5 mW/ch

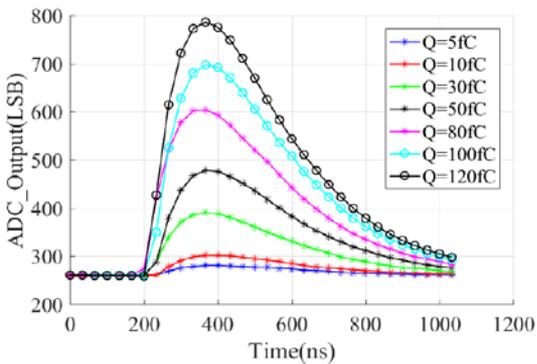
Tests of the ASIC chip



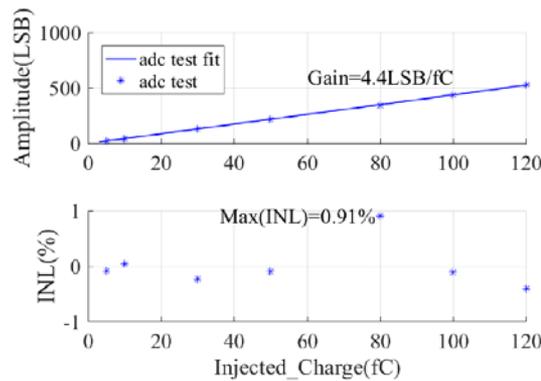
- The floor plan in layout :
 - The die size of 1950 μm x 2160 μm
 - Analog Front-End , SPI, SAR ADC, LVDS driver are supplied by separate power
- The ASIC have been taped out in November, 2019 and is being evaluated

Layout of ASIC chip

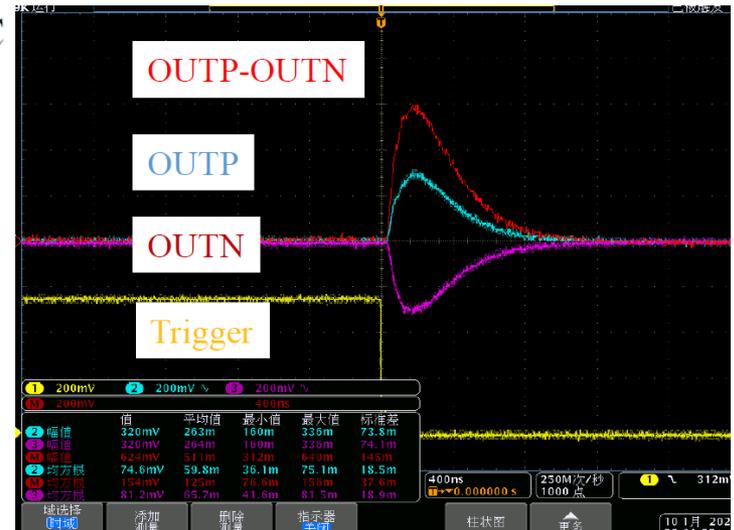
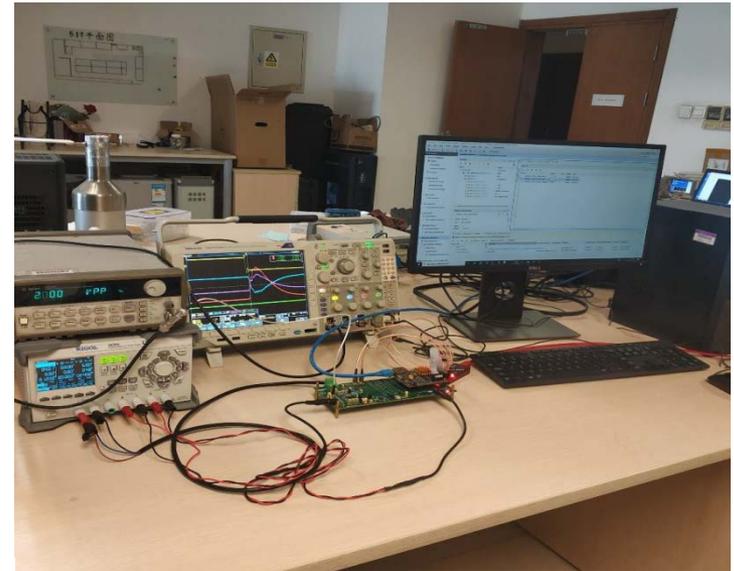
- Transient outputs



- The linearity @ gain = 10 mV/fC



Gain = 4.4 LSB/fC = 4.4 x 2.34 mV/fC = 10.3 mV/fC



Results of ASIC chip

- A 16 channel low power readout ASIC for TPC readout have been developed
 - The power consumption is **2.33 mW/channel**:
 - $P_{AFE}=1.43$ mW/channel
 - $P_{ADC} = 0.9$ mW/channel @ 40MS/s
 - ENC = **852 e** @ $C_{in}=2$ pF, gain=10 mV/fC and can be reduced to **474 e** using digital trapezoidal filter
- Future Plan
 - More ASIC evaluations: higher sampling rate, more detailed noise test, test with detectors...
 - Low power digital filter and data compression in FPGA/ASIC

Summary

- Some motivations of TPC detector for the circular collider at high luminosity Z pole listed.
- Some update results of TPC module have been studies, **it can effectively reduce ions at the low gain** without the space charge and discharge.
- 266nm UV laser beams system will be very useful in the TPC module and prototype R&D.
- The detector module **will assembled and commissioned** with the low power consumption ASIC chip in 2021.

Thanks for your attention.